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Band structure and device fabrication using thin-films of p-benzoquinonemonoimine zwitterion/P3HT blends¹ STEPHANIE RO-DRIGUEZ MARMOL, GERSON DIAZ, FREDDY WONG, GRACE FONTANEZ, FERNAND TORRES, EDUARDO VEGA, Univ of Puerto Rico - Humacao, LU-CIE ROUTABOUL, PIERRE BRAUNSTIEN, Universit de Strasbourg, YANG LIU, XIN ZHANG, PETER DOWBEN, University of Nebraska, BERNARD DOUDIN, Universit Louis Pasteur Strasbourg, LUIS G. ROSA, Univ of Puerto Rico - Humacao, University of Nebraska — The electronic structure of some pbenzoquinonemonoimine zwitterion molecular films have a definite, although small, density of states evident at the Fermi-level as well as a nonzero inner potential and thus is very different from a true insulator. Photoelectron emission spectroscopy studies of polymer blends of three types of p-benzoquinonemonoimine zwitterion and regio-regular poly(3-hexylthiophene) (P3HT) thin-films provide evidence of changes in the molecular band structure due to interaction of such bands. Electric drainsource measurements done with these polymer blends show evidence of higher transport currents in comparison to P3HT polymer thin-films alone for one of the blends.

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